

isc Silicon PNP Power Transistor

NJW0302G

DESCRIPTION

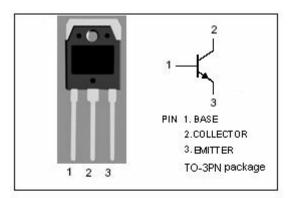
- High Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= -250V(Min)
- · Good Linearity of hFE
- Complement to Type NJW0281G
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

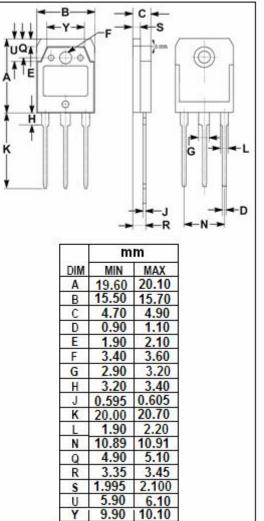
APPLICATIONS

• Designed for high fidelity audio amplifier and other linear applications

SYMBOL	PARAMETER	VALUE	UNIT	
V _{сво}	Collector-Base Voltage	ige -250		
V _{CEO}	Collector-Emitter Voltage	-250	V	
V _{EBO}	Emitter-Base Voltage -5		V	
lc	Collector Current-Continuous -15		A	
I _B	Base Current-Continuous	-1.5	A	
Pc	Collector Power Dissipation @ T _C =25°C	150	W	
TJ	Junction Temperature	150	°C	
Tstg	Storage Temperature Range	-65~150	°C	

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -30mA ; I _B = 0	-250			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -5.0A; I _B = -0.5A			-1.0	V
V _{BE(on)}	Base-Emitter On Voltage	$I_{\rm C}$ = -5.0 A, $V_{\rm CE}$ = -5.0 V			-1.2	V
Ісво	Collector Cutoff Current	V _{CB} = -250V ; I _E = 0			-10	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-5	μA
h _{FE}	DC Current Gain	I _C = -0.5A ; V _{CE} = -5V	75		150	
h _{FE-1}	DC Current Gain	I _C = -1A ; V _{CE} = 5V	75		150	
h _{FE-2}	DC Current Gain	I _C = -3A ; V _{CE} = -5V	75		150	

NOTICE:

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